



PI74ALVCH16260

12-Bit To 24-Bit Multiplexed D-Type Latch with 3-State Outputs

Product Features

- PI74ALVCH16260 is designed for low voltage operation
- $V_{CC} = 2.3V$ to $3.6V$
- Hysteresis on all inputs
- Typical V_{OLP} (Output Ground Bounce)
 $< 0.8V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Typical V_{OHV} (Output V_{OH} Undershoot)
 $< 2.0V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Bus Hold retains last active bus state during 3-State, eliminating the need for external pullup resistors
- Industrial operation at $-40^\circ C$ to $+85^\circ C$
- Packages available:
 - 56-pin 240 mil wide plastic TSSOP (A)
 - 56-pin 300 mil wide plastic SSOP (V)

Product Description

Pericom Semiconductor's PI74ALVCH series of logic circuits are produced using the Company's advanced 0.5 micron CMOS technology, achieving industry leading speed.

The PI74ALVCH16260 is a 12-bit to 24-bit multiplexed D-type latch designed for 2.3V to 3.6 V_{CC} operation. It is used in applications where two separate datapaths must be multiplexed onto, or demultiplexed from, a single data path.

Typical applications include multiplexing and/or demultiplexing address and data information in microprocessor or bus-interface and in memory-interleaving.

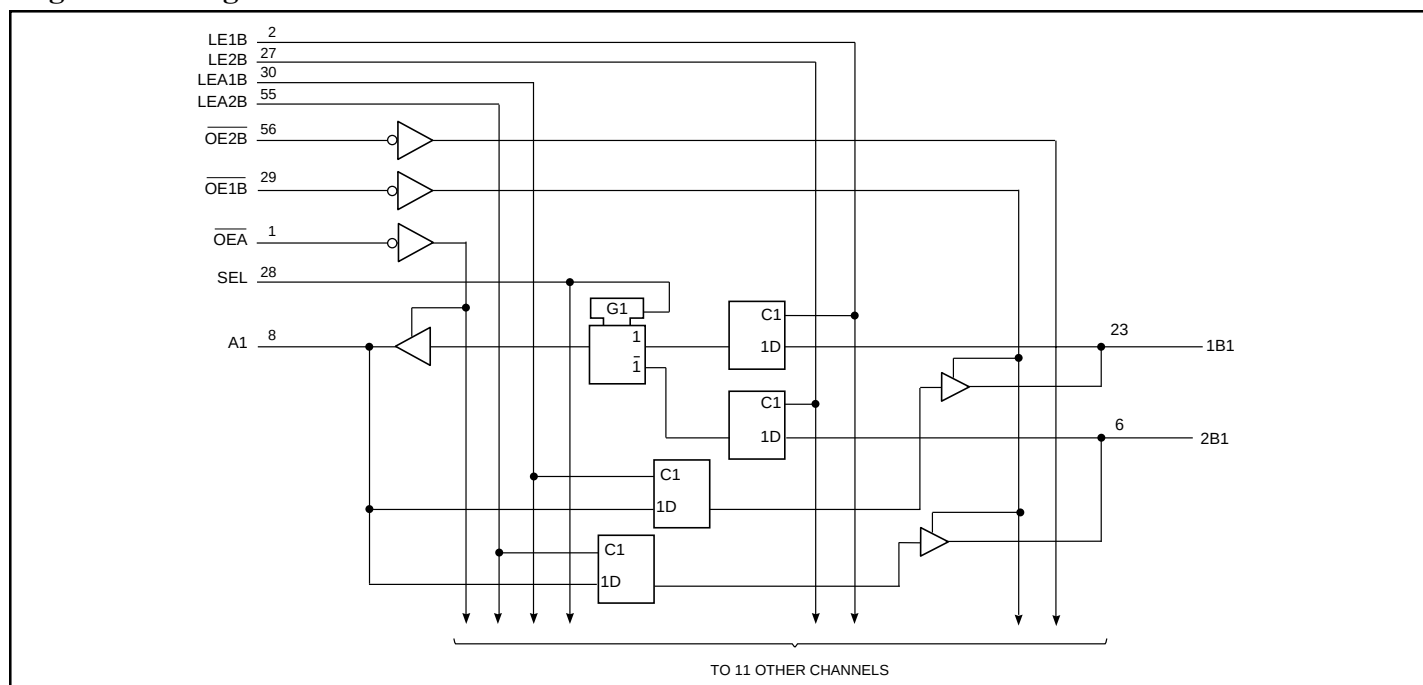
Three 12-bit I/O ports (A1-A12, 1B1-1B12, and 2B1-2B12) are available for address and/or data transfer. The output-enable ($\overline{OE1B}$, $\overline{OE2B}$, and $\overline{OEA}$) inputs control bus transceiver functions. The $\overline{OE1B}$ and $\overline{OE2B}$ control signals also allow bank control in the A-to-B direction.

Address and/or data information can be stored using the internal storage latches. The latch-enable ($\overline{LE1B}$, $\overline{LE2B}$, $\overline{LEA1B}$, and $\overline{LEA2B}$) inputs are used to control data storage. When the latch-enable input is HIGH, the latch is transparent. When the latch-enable input goes LOW, the data present at the inputs is latched and remains latched until the latch-enable input is returned HIGH.

To ensure high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor whose minimum value is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Logic Block Diagram



Truth Tables⁽¹⁾

Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
SEL	Select
LE	Latch Enable
A,1B,2B	Data Inputs
A,1B,2B	3-State Outputs
GND	Ground
V _{CC}	Power

B to A ($\overline{OE}B = H$)

Inputs						Output A
1B	2B	SEL	LE1B	LE2B	$\overline{OE}A$	
H	X	H	H	X	L	H
L	X	H	H	X	L	L
X	X	H	L	X	L	A0
X	H	L	X	H	L	H
X	L	L	X	H	L	L
X	X	L	X	L	L	A0
X	X	X	X	X	H	Z

Product Pin Configuration

$\overline{OE}A$	1	56	$\overline{OE}2B$
LE1B	2	55	LEA2B
2B3	3	54	2B4
GND	4	53	GND
2B2	5	52	2B5
2B1	6	51	2B6
V _{CC}	7	50	V _{CC}
A1	8	49	2B7
A2	9	48	2B8
A3	10	47	2B9
GND	11	46	GND
A4	12	45	2B10
A5	13	44	2B11
A6	14	43	2B12
A7	15	42	1B12
A8	16	41	1B11
A9	17	40	1B10
GND	18	39	GND
A10	19	38	1B9
A11	20	37	1B8
A12	21	36	1B7
V _{CC}	22	35	V _{CC}
1B1	23	34	1B6
1B2	24	33	1B5
GND	25	32	GND
1B3	26	31	1B4
LE2B	27	30	LEA1B
SEL	28	29	$\overline{OE}1B$

A to B ($\overline{OE}A = H$)

Inputs					Outputs	
A	LEA1B	LEA2B	$\overline{OE}1B$	$\overline{OE}2B$	1B	2B
H	H	H	L	L	H	H
L	H	H	L	L	L	L
H	H	L	L	L	H	2B0
L	H	L	L	L	L	2B0
H	L	H	L	L	1B0	H
L	L	H	L	L	1B0	L
X	L	L	L	L	1B0	2B0
X	X	X	H	H	Z	Z
X	X	X	L	H	Active	Z
X	X	X	H	L	Z	Active
X	X	X	L	L	Active	Active

Note:

- H = High Signal Level
L = Low Signal Level
X = Irrelevant
Z = High Impedance

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Input Voltage Range, V_{IN}	–0.5V to $V_{CC}+0.5V$
Output Voltage Range, V_{OUT}	–0.5V to $V_{CC}+0.5V$
DC Input Voltage	–0.5V to +5.0V
DC Output Current	100mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 3.3V \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
V_{CC}	Supply Voltage		2.3		3.6	V
$V_{IH}^{(3)}$	Input HIGH Voltage	$V_{CC} = 2.3V$ to $2.7V$	1.7			
		$V_{CC} = 2.7V$ to $3.6V$	2.0			
$V_{IL}^{(3)}$	Input LOW Voltage	$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 2.7V$ to $3.6V$			0.8	
$V_{IN}^{(3)}$	Input Voltage		0		V_{CC}	
$V_{OUT}^{(3)}$	Output Voltage		0		V_{CC}	
V_{OH}	Output HIGH Voltage	$I_{OH} = -100\mu A$, $V_{CC} = \text{Min. to Max.}$	$V_{CC} - 0.2$			
		$V_{IH} = 1.7V$, $I_{OH} = -6mA$, $V_{CC} = 2.3V$	2.0			
		$V_{IH} = 1.7V$, $I_{OH} = -12mA$, $V_{CC} = 2.3V$	1.7			
		$V_{IH} = 2.0V$, $I_{OH} = -12mA$, $V_{CC} = 2.7V$	2.2			
		$V_{IH} = 2.0V$, $I_{OH} = -12mA$, $V_{CC} = 3.0V$	2.4			
		$V_{IH} = 2.0V$, $I_{OH} = -24mA$, $V_{CC} = 3.0V$	2.0			
V_{OL}	Output LOW Voltage	$I_{OL} = 100\mu A$, $V_{IL} = \text{Min. to Max.}$			0.2	
		$V_{IL} = 0.7V$, $I_{OL} = 6mA$, $V_{CC} = 2.3V$			0.4	
		$V_{IL} = 0.7V$, $I_{OL} = 12mA$, $V_{CC} = 2.3V$			0.7	
		$V_{IL} = 0.8V$, $I_{OL} = 12mA$, $V_{CC} = 2.7V$			0.4	
		$V_{IL} = 0.8V$, $I_{OL} = 24mA$, $V_{CC} = 3.0V$			0.55	
$I_{OH}^{(3)}$	Output HIGH Current	$V_{CC} = 2.3V$			–12	mA
		$V_{CC} = 2.7V$			–12	
		$V_{CC} = 3.0V$			–24	
$I_{OL}^{(3)}$	Output LOW Current	$V_{CC} = 2.3V$			12	
		$V_{CC} = 2.7V$			12	
		$V_{CC} = 3.0V$			24	

DC Electrical Characteristics-Continued (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 3.3\text{V} \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I_{IN}	Input Current	$V_{IN} = V_{CC}$ or GND, $V_{CC} = 3.6\text{V}$			± 5	μA
$I_{IN (HOLD)}$	Input Hold Current	$V_{IN} = 0.7\text{V}$, $V_{CC} = 2.3\text{V}$	45			
		$V_{IN} = 1.7\text{V}$, $V_{CC} = 2.3\text{V}$	-45			
		$V_{IN} = 0.8\text{V}$, $V_{CC} = 3.0\text{V}$	75			
		$V_{IN} = 2.0\text{V}$, $V_{CC} = 3.0\text{V}$	-75			
		$V_{IN} = 0$ to 3.6V , $V_{CC} = 3.6\text{V}$			± 500	
I_{OZ}	Output Current (3-State Outputs)	$V_{OUT} = V_{CC}$ or GND, $V_{CC} = 3.6\text{V}$			± 10	μA
I_{CC}	Supply Current	$V_{CC} = 3.6\text{V}$, $I_{OUT} = 0\mu\text{A}$, $V_{IN} = \text{GND}$ or V_{CC}			40	
ΔI_{CC}	Supply Current per Input @ TTL HIGH	$V_{CC} = 3.0\text{V}$ to 3.6V One Input at $V_{CC} - 0.6\text{V}$ Other Inputs at V_{CC} or GND			750	
C_I	Control Inputs	$V_{IN} = V_{CC}$ or GND, $V_{CC} = 3.3\text{V}$		3.5		pF
C_O	Outputs	$V_O = V_{CC}$ or GND, $V_{CC} = 3.3\text{V}$		9		

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient and maximum loading.
3. Unused Control Inputs must be held HIGH or LOW to prevent them from floating.

Timing Requirements over Operating Range

Parameters	Description	$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 2.7\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_W	Pulse duration, LE1B, LE2B, LEA1B, or LEA2B High	3.3		3.3		3.3		ns
t_{SU}	Setup time, data before LE1B, LE2B, LEA1B, or LEA2B	1.4		1.1		1.1		
t_H	Hold time, data after LE1B, LE2B, LEA1B or LEA2B	1.6		1.9		1.5		
$\Delta t / \Delta V^{(1)}$	Input Transition Rise or Fall	0	10	0	10	0	10	ns/V

Note:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

Switching Characteristics over Operating Range⁽¹⁾

Parameters	From (Input)	To (Output)	$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		Units
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max. ⁽²⁾	
t_{PD}	A or B	B or A	1.2	6.0		5.1	1.2	4.3	ns
	LE	A or B	1.0	6.2		5.2	1.0	4.4	
	SEL	A	1.2	7.5		6.6	1.1	5.6	
t_{EN}	$\overline{OE}$	A or B	1.0	7.2		6.4	1.0	5.4	
t_{DIS}	$\overline{OE}$	A or B	1.7	5.9		5.0	1.3	4.6	

Notes:

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.

Operating Characteristics, $T_A = 25^\circ C$

Parameter		Test Conditions	V _{CC} = 2.5V ± 0.2V	V _{CC} = 3.3V ± 0.3V	Units
			Typical		
C _{PD} Power Dissipation Capacitance	Outputs Enabled	C _L = 50pF, f = 10 MHz	87	120	pF
	Outputs Disabled		80.5	118	

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ ⁽²⁾	Max.	Units
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$, $I_{out} = 0V$, $V_{in} = \text{GND or } V_{CC}$			40	μA
ΔI_{CC}	Supply Current per Input @TTL HIGH	$V_{CC} = 3.0V \text{ to } 3.6V$, One input at $V_{CC} - 0.6V$ Other inputs at V_{CC} or GND			750	

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.